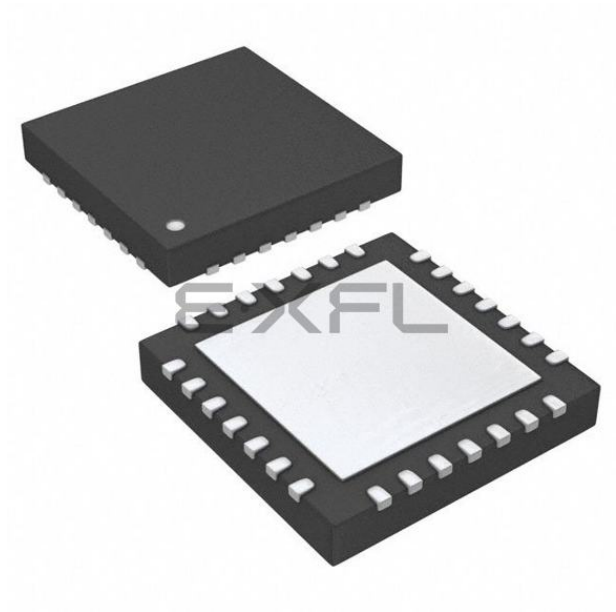

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Peripherals	Brown-out Detect/Reset, HLVD, POR, PWM, WDT
Number of I/O	24
Program Memory Size	16KB (5.5K x 24)
Program Memory Type	FLASH
EEPROM Size	512 x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	28-VQFN Exposed Pad
Supplier Device Package	28-QFN (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic24f16kl402-e-ml

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TABLE 1-4: PIC24F16KL40X/30X FAMILY PINOUT DESCRIPTIONS

Function	Pin Number				I/O	Buffer	Description
	20-Pin PDIP/ SSOP/ SOIC	20-Pin QFN	28-Pin SPDIP/ SSOP/ SOIC	28-Pin QFN			
AN0	2	19	2	27	I	ANA	A/D Analog Inputs. Not available on PIC24F16KL30X family devices.
AN1	3	20	3	28	I	ANA	
AN2	4	1	4	1	I	ANA	
AN3	5	2	5	2	I	ANA	
AN4	6	3	6	3	I	ANA	
AN5	—	—	7	4	I	ANA	
AN9	18	15	26	23	I	ANA	
AN10	17	14	25	22	I	ANA	
AN11	16	13	24	21	I	ANA	
AN12	15	12	23	20	I	ANA	
AN13	7	4	9	6	I	ANA	
AN14	8	5	10	7	I	ANA	
AN15	9	6	11	8	I	ANA	
ASCL1	—	—	15	12	I/O	I^2C™	Alternate MSSP1 I^2C Clock Input/Output
ASDA1	—	—	14	11	I/O	I^2C	Alternate MSSP1 I^2C Data Input/Output
AVDD	20	17	28	25	I	ANA	Positive Supply for Analog modules
AVSS	19	16	27	24	I	ANA	Ground Reference for Analog modules
CCP1	14	11	20	17	I/O	ST	CCP1/ECCP1 Capture Input/Compare and PWM Output
CCP2	15	12	23	20	I/O	ST	CCP2 Capture Input/Compare and PWM Output
CCP3	13	10	19	16	I/O	ST	CCP3 Capture Input/Compare and PWM Output
C1INA	8	5	7	4	I	ANA	Comparator 1 Input A (+)
C1INB	7	4	6	3	I	ANA	Comparator 1 Input B (-)
C1INC	5	2	5	2	I	ANA	Comparator 1 Input C (+)
C1IND	4	1	4	1	I	ANA	Comparator 1 Input D (-)
C1OUT	17	14	25	22	O	—	Comparator 1 Output
C2INA	5	2	5	2	I	ANA	Comparator 2 Input A (+)
C2INB	4	1	4	1	I	ANA	Comparator 2 Input B (-)
C2INC	8	5	7	4	I	ANA	Comparator 2 Input C (+)
C2IND	7	4	6	3	I	ANA	Comparator 2 Input D (-)
C2OUT	14	11	20	17	O	—	Comparator 2 Output
CLK I	7	4	9	6	I	ANA	Main Clock Input
CLKO	8	5	10	7	O	—	System Clock Output

Legend: TTL = TTL input buffer
ANA = Analog level input/output
ST = Schmitt Trigger input buffer
I^2C = I^2C™/SMBus input buffer

TABLE 1-5: PIC24F16KL20X/10X FAMILY PINOUT DESCRIPTIONS (CONTINUED)

Function	Pin Number			I/O	Buffer	Description
	20-Pin PDIP/ SSOP/ SOIC	20-Pin QFN	14-Pin PDIP/ TSSOP			
CVREF	17	14	11	I	ANA	Comparator Voltage Reference Output
CVREF+	2	19	2	I	ANA	Comparator Reference Positive Input Voltage
CVREF-	3	20	3	I	ANA	Comparator Reference Negative Input Voltage
HLVDIN	15	12	6	I	ST	High/Low-Voltage Detect Input
INT0	11	8	12	I	ST	Interrupt 0 Input
INT1	17	14	11	I	ST	Interrupt 1 Input
INT2	14	11	10	I	ST	Interrupt 2 Input
$\overline{MCLR}$	1	18	1	I	ST	Master Clear (device Reset) Input. This line is brought low to cause a Reset.
OSCI	7	4	4	I	ANA	Main Oscillator Input
OSCO	8	5	5	O	ANA	Main Oscillator Output
PGEC1	5	2	—	I/O	ST	ICSP™ Clock 1
PCED1	4	1	—	I/O	ST	ICSP Data 1
PGEC2	2	19	2	I/O	ST	ICSP Clock 2
PGED2	3	20	3	I/O	ST	ICSP Data 2
PGEC3	10	7	7	I/O	ST	ICSP Clock 3
PGED3	9	6	6	I/O	ST	ICSP Data 3
RA0	2	19	2	I/O	ST	PORTA Pins
RA1	3	20	3	I/O	ST	
RA2	7	4	4	I/O	ST	
RA3	8	5	5	I/O	ST	
RA4	10	7	7	I/O	ST	
RA5	1	18	1	I	ST	
RA6	14	11	10	I/O	ST	
RB0	4	1	—	I/O	ST	PORTB Pins
RB1	5	2	—	I/O	ST	
RB2	6	3	—	I/O	ST	
RB4	9	6	6	I/O	ST	
RB7	11	8	—	I/O	ST	
RB8	12	9	8	I/O	ST	
RB9	13	10	9	I/O	ST	
RB12	15	12	—	I/O	ST	
RB13	16	13	—	I/O	ST	
RB14	17	14	11	I/O	ST	
RB15	18	15	12	I/O	ST	
REFO	18	15	12	O	—	Reference Clock Output

Legend: TTL = TTL input buffer
ANA = Analog level input/output
ST = Schmitt Trigger input buffer
I^2C = I^2C™/SMBus input buffer

TABLE 4-5: INTERRUPT CONTROLLER REGISTER MAP

File Name	Addr	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	All Resets
INTCON1	0080	NSTDIS	—	—	—	—	—	—	—	—	—	—	MATHERR	ADDRERR	STKERR	OSCFAIL	—	0000
INTCON2	0082	ALTIVT	DISI	—	—	—	—	—	—	—	—	—	—	—	INT2EP	INT1EP	INT0EP	0000
IFS0	0084	NVMIF	—	AD1IF	U1TXIF	U1RXIF	—	—	T3IF	T2IF	CCP2IF	—	—	T1IF	CCP1IF	—	INT0IF	0000
IFS1	0086	U2TXIF	U2RXIF	INT2IF	—	T4IF(1)	—	CCP3IF(1)	—	—	—	—	INT1IF	CNIF	CMIF	BCL1IF	SSP1IF	0000
IFS2	0088	—	—	—	—	—	—	—	—	—	—	T3GIF	—	—	—	—	—	0000
IFS3	008A	—	—	—	—	—	—	—	—	—	—	—	—	—	BCL2IF(1)	SSP2IF(1)	—	0000
IFS4	008C	—	—	—	—	—	—	—	HLVDIF	—	—	—	—	—	U2ERIF	U1ERIF	—	0000
IFS5	008E	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	ULPWUIF	0000
IEC0	0094	NVMIE	—	AD1IE	U1TXIE	U1RXIE	—	—	T3IE	T2IE	CCP2IE	—	—	T1IE	CCP1IE	—	INT0IE	0000
IEC1	0096	U2TXIE	U2RXIE	INT2IE	—	T4IE(1)	—	CCP3IE(1)	—	—	—	—	INT1IE	CNIE	CMIE	BCL1IE	SSP1IE	0000
IEC2	0098	—	—	—	—	—	—	—	—	—	—	T3GIE	—	—	—	—	—	0000
IEC3	009A	—	—	—	—	—	—	—	—	—	—	—	—	—	BCL2IE(1)	SSP2IE(1)	—	0000
IEC4	009C	—	—	—	—	—	—	—	HLVDIE	—	—	—	—	—	U2ERIE	U1ERIE	—	0000
IEC5	009E	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	ULPWUIE	0000
IPC0	00A4	—	T1IP2	T1IP1	T1IP0	—	CCP1IP2	CCP1IP1	CCP1IP0	—	—	—	—	—	INT0IP2	INT0IP1	INT0IP0	4404
IPC1	00A6	—	T2IP2	T2IP1	T2IP0	—	CCP2IP2	CCP2IP1	CCP2IP0	—	—	—	—	—	—	—	—	4400
IPC2	00A8	—	U1RXIP2	U1RXIP1	U1RXIP0	—	—	—	—	—	—	—	—	—	T3IP2	T3IP1	T3IP0	4004
IPC3	00AA	—	NVMIP2	NVMIP1	NVMIP0	—	—	—	—	—	AD1IP2	AD1IP1	AD1IP0	—	U1TXIP2	U1TXIP1	U1TXIP0	4044
IPC4	00AC	—	CNIP2	CNIP1	CNIP0	—	CMIP2	CMIP1	CMIP0	—	BCL1IP2	BCL1IP1	BCL1IP0	—	SSP1IP2	SSP1IP1	SS1IP0	4444
IPC5	00AE	—	—	—	—	—	—	—	—	—	—	—	—	—	INT1IP2	INT1IP1	INT1IP0	0004
IPC6	00B0	—	T4IP2(1)	T4IP1(1)	T4IP0(1)	—	—	—	—	—	CCP3IP2(1)	CCP3IP1(1)	CCP3IP0(1)	—	—	—	—	4040
IPC7	00B2	—	U2TXIP2	U2TXIP1	U2TXIP0	—	U2RXIP2	U2RXIP1	U2RXIP0	—	INT2IP2	INT2IP1	INT2IP0	—	—	—	—	4440
IPC9	00B6	—	—	—	—	—	—	—	—	—	T3GIP2	T3GIP1	T3GIP0	—	—	—	—	0040
IPC12	00BC	—	—	—	—	—	BCL2IP2(1)	BCL2IP1(1)	BCL2IP0(1)	—	SSP2IP2(1)	SSP2IP1(1)	SSP2IP0(1)	—	—	—	—	0440
IPC16	00C4	—	—	—	—	—	U2ERIP2	U2ERIP1	U2ERIP0	—	U1ERIP2	U1ERIP1	U1ERIP0	—	—	—	—	0440
IPC18	00C8	—	—	—	—	—	—	—	—	—	—	—	—	—	HLVDIP2	HLVDIP1	HLVDIP0	0004
IPC20	00CC	—	—	—	—	—	—	—	—	—	—	—	—	—	ULPWUIP2	ULPWUIP1	ULPWUIP0	0004
INTTREG	00E0	CPUIRQ	r	VHOLD	—	ILR3	ILR2	ILR1	ILR0	—	VECNUM6	VECNUM5	VECNUM4	VECNUM3	VECNUM2	VECNUM1	VECNUM0	0000

Legend: — = unimplemented, read as '0', r = reserved. Reset values are shown in hexadecimal.

Note 1: These bits are unimplemented on PIC24FXXKL10X and PIC24FXXKL20X family devices; read as '0'.

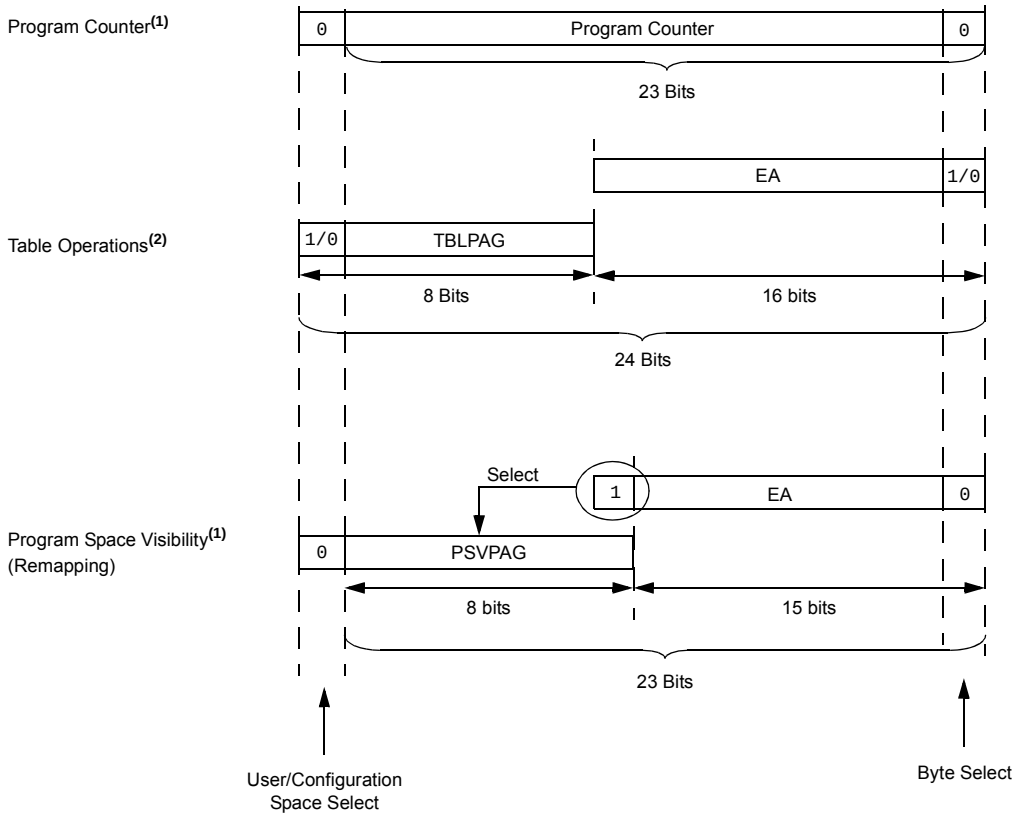
TABLE 4-20: PROGRAM SPACE ADDRESS CONSTRUCTION

Access Type	Access Space	Program Space Address				
		<23>	<22:16>	<15>	<14:1>	<0>
Instruction Access (Code Execution)	User	0	PC<22:1>			0
		0xx xxxx xxxx xxxx xxxx xxx0				
TBLRD/TBLWT (Byte/Word Read/Write)	User	TBLPAG<7:0>		Data EA<15:0>		
		0xxx xxxx		xxxx xxxx xxxx xxxx		
	Configuration	TBLPAG<7:0>		Data EA<15:0>		
		1xxx xxxx		xxxx xxxx xxxx xxxx		
Program Space Visibility (Block Remap/Read)	User	0	PSVPAG<7:0>(2)		Data EA<14:0>(1)	
		0	xxxx xxxx		xxx xxxx xxxx xxxx	

Note 1: Data EA<15> is always '1' in this case, but is not used in calculating the program space address. Bit 15 of the address is PSVPAG<0>.

2: PSVPAG can have only two values ('00' to access program memory and FF to access data EEPROM) on PIC24F16KL402 family devices.

FIGURE 4-5: DATA ACCESS FROM PROGRAM SPACE ADDRESS GENERATION



Note 1: The LSb of program space addresses is always fixed as '0' in order to maintain word alignment of data in the program and data spaces.

2: Table operations are not required to be word-aligned. Table read operations are permitted in the configuration memory space.

5.5.1 PROGRAMMING ALGORITHM FOR FLASH PROGRAM MEMORY

The user can program one row of Flash program memory at a time by erasing the programmable row. The general process is as follows:

1. Read a row of program memory (32 instructions) and store in data RAM.
2. Update the program data in RAM with the desired new data.
3. Erase a row (see Example 5-1):
   a) Set the NVMOPx bits (NVMCON<5:0>) to '011000' to configure for row erase. Set the ERASE (NVMCON<6>) and WREN (NVMCON<14>) bits.
   b) Write the starting address of the block to be erased into the TBLPAG and W registers.
   c) Write 55h to NVMKEY.
   d) Write AAh to NVMKEY.
   e) Set the WR bit (NVMCON<15>). The erase cycle begins and the CPU stalls for the duration of the erase cycle. When the erase is done, the WR bit is cleared automatically.
4. Write the first 32 instructions from data RAM into the program memory buffers (see Example 5-1).
5. Write the program block to Flash memory:
   a) Set the NVMOPx bits to '000100' to configure for row programming. Clear the ERASE bit and set the WREN bit.
   b) Write 55h to NVMKEY.
   c) Write AAh to NVMKEY.
   d) Set the WR bit. The programming cycle begins and the CPU stalls for the duration of the write cycle. When the write to Flash memory is done, the WR bit is cleared automatically.

For protection against accidental operations, the write initiate sequence for NVMKEY must be used to allow any erase or program operation to proceed. After the programming command has been executed, the user must wait for the programming time until programming is complete. The two instructions following the start of the programming sequence should be NOPs, as shown in Example 5-5.

EXAMPLE 5-1: ERASING A PROGRAM MEMORY ROW – ASSEMBLY LANGUAGE CODE

```
; Set up NVMCON for row erase operation
        MOV     #0x4058, W0                 ;
        MOV     W0, NVMCON                  ; Initialize NVMCON
; Init pointer to row to be ERASED
        MOV     #tblpage(PROG_ADDR), W0     ;
        MOV     W0, TBLPAG                  ; Initialize PM Page Boundary SFR
        MOV     #tbloffset(PROG_ADDR), W0   ; Initialize in-page EA[15:0] pointer
        TBLWTL  W0, [W0]                    ; Set base address of erase block
        DISI    #5                          ; Block all interrupts
                                              for next 5 instructions
        MOV     #0x55, W0
        MOV     W0, NVMKEY                  ; Write the 55 key
        MOV     #0xAA, W1                   ;
        MOV     W1, NVMKEY                  ; Write the AA key
        BSET    NVMCON, #WR                 ; Start the erase sequence
        NOP                                 ; Insert two NOPs after the erase
        NOP                                 ; command is asserted
```

EXAMPLE 5-4: LOADING THE WRITE BUFFERS – 'C' LANGUAGE CODE

```
// C example using MPLAB C30

  #define NUM_INSTRUCTION_PER_ROW 64
   int __attribute__ ((space(auto_psv))) progAddr = &progAddr; // Global variable located in Pgm Memory
  unsigned int offset;
  unsigned int i;
  unsigned int progData[2*NUM_INSTRUCTION_PER_ROW];          // Buffer of data to write

  //Set up NVMCON for row programming
  NVMCON = 0x4004;                                          // Initialize NVMCON

  //Set up pointer to the first memory location to be written
  TBLPAG = __builtin_tblpage(&progAddr);                    // Initialize PM Page Boundary SFR
  offset = &progAddr & 0xFFFF;                              // Initialize lower word of address

  //Perform TBLWT instructions to write necessary number of latches
  for(i=0; i < 2*NUM_INSTRUCTION_PER_ROW; i++)
  {
      __builtin_tblwtl(offset, progData[i++]);              // Write to address low word
      __builtin_tblwth(offset, progData[i]);                // Write to upper byte
      offset = offset + 2;                                  // Increment address
   }
```

EXAMPLE 5-5: INITIATING A PROGRAMMING SEQUENCE – ASSEMBLY LANGUAGE CODE

```
        DISI    #5                      ; Block all interrupts
                                          for next 5 instructions
        MOV     #0x55, W0
        MOV     W0, NVMKEY              ; Write the 55 key
        MOV     #0xAA, W1               ;
        MOV     W1, NVMKEY              ; Write the AA key
        BSET    NVMCON, #WR             ; Start the erase sequence
        NOP                             ; 2 NOPs required after setting WR
        NOP                             ;
        BTSC    NVMCON, #15             ; Wait for the sequence to be completed
        BRA     $-2                     ;
```

EXAMPLE 5-6: INITIATING A PROGRAMMING SEQUENCE – 'C' LANGUAGE CODE

```
// C example using MPLAB C30

asm("DISI #5");              // Block all interrupts for next 5 instructions

__builtin_write_NVM();       // Perform unlock sequence and set WR
```

6.0 DATA EEPROM MEMORY

Note: This data sheet summarizes the features of this group of PIC24F devices. It is not intended to be a comprehensive reference source. For more information on Data EEPROM, refer to the *"dsPIC33/PIC24 Family Reference Manual"*, **"Data EEPROM"** (DS39720).

The data EEPROM memory is a Nonvolatile Memory (NVM), separate from the program and volatile data RAM. Data EEPROM memory is based on the same Flash technology as program memory, and is optimized for both long retention and a higher number of erase/write cycles.

The data EEPROM is mapped to the top of the user program memory space, with the top address at program memory address, 7FFFFFh. For PIC24FXXKL4XX devices, the size of the data EEPROM is 256 words (7FFE00h to 7FFFFFh). For PIC24FXXKL3XX devices, the size of the data EEPROM is 128 words (7FFF00h to 7FFFFFh). The data EEPROM is not implemented in PIC24F08KL20X or PIC24F04KL10X devices.

The data EEPROM is organized as 16-bit wide memory. Each word is directly addressable, and is readable and writable during normal operation over the entire VDD range.

Unlike the Flash program memory, normal program execution is not stopped during a data EEPROM program or erase operation.

The data EEPROM programming operations are controlled using the three NVM Control registers:

- NVMCON: Nonvolatile Memory Control Register
- NVMKEY: Nonvolatile Memory Key Register
- NVMADR: Nonvolatile Memory Address Register

6.1 NVMCON Register

The NVMCON register (Register 6-1) is also the primary control register for data EEPROM program/erase operations. The upper byte contains the control bits used to start the program or erase cycle, and the flag bit to indicate if the operation was successfully performed. The lower byte of NVMCOM configures the type of NVM operation that will be performed.

6.2 NVMKEY Register

The NVMKEY is a write-only register that is used to prevent accidental writes or erasures of data EEPROM locations.

To start any programming or erase sequence, the following instructions must be executed first, in the exact order provided:

1. Write 55h to NVMKEY.
2. Write AAh to NVMKEY.

After this sequence, a write will be allowed to the NVMCON register for one instruction cycle. In most cases, the user will simply need to set the WR bit in the NVMCON register to start the program or erase cycle. Interrupts should be disabled during the unlock sequence.

The MPLAB® C30 C compiler provides a defined library procedure (`builtin_write_NVM`) to perform the unlock sequence. Example 6-1 illustrates how the unlock sequence can be performed with in-line assembly.

EXAMPLE 6-1: DATA EEPROM UNLOCK SEQUENCE

```
//Disable Interrupts For 5 instructions
asm volatile("disi #5");
//Issue Unlock Sequence
asm volatile ("mov #0x55, W0      \n"
              "mov W0, NVMKEY     \n"
              "mov #0xAA, W1      \n"
              "mov W1, NVMKEY     \n");
// Perform Write/Erase operations
asm volatile ("bset NVMCON, #WR   \n"
              "nop                \n"
              "nop                \n");
```

REGISTER 8-13: IEC2: INTERRUPT ENABLE CONTROL REGISTER 2

U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0
—	—	—	—	—	—	—	—
bit 15							bit 8

U-0	U-0	R/W-0	U-0	U-0	U-0	U-0	U-0
—	—	T3GIE	—	—	—	—	—
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'	
-n = Value at POR	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 15-6 **Unimplemented:** Read as '0'

bit 5 **T3GIF:** Timer3 External Gate Interrupt Enable bit
1 = Interrupt request is enabled
0 = Interrupt request is not enabled

bit 4-0 **Unimplemented:** Read as '0'

REGISTER 8-14: IEC3: INTERRUPT ENABLE CONTROL REGISTER 3

U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0
—	—	—	—	—	—	—	—
bit 15							bit 8

U-0	U-0	U-0	U-0	U-0	R/W-0	R/W-0	U-0
—	—	—	—	—	BCL2IE(1)	SSP2IE(1)	—
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'	
-n = Value at POR	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 15-3 **Unimplemented:** Read as '0'

bit 2 **BCL2IE:** MSSP2 I^2C™ Bus Collision Interrupt Enable bit(1)
1 = Interrupt request is enabled
0 = Interrupt request is not enabled

bit 1 **SSP2IF:** MSSP2 SPI/I^2C Event Interrupt Enable bit(1)
1 = Interrupt request is enabled
0 = Interrupt request is not enabled

bit 0 **Unimplemented:** Read as '0'

Note 1: These bits are unimplemented on PIC24FXXKL10X and PIC24FXXKL20X devices.

10.2.1 SLEEP MODE

Sleep mode includes these features:

- The system clock source is shut down. If an on-chip oscillator is used, it is turned off.
- The device current consumption will be reduced to a minimum, provided that no I/O pin is sourcing current.
- The I/O pin directions and states are frozen.
- The Fail-Safe Clock Monitor does not operate during Sleep mode since the system clock source is disabled.
- The LPRC clock will continue to run in Sleep mode if any active module has selected the LPRC as its source, including the WDT, Timer1 and Timer3.
- The WDT, if enabled, is automatically cleared prior to entering Sleep mode.
- Some device features, or peripherals, may continue to operate in Sleep mode. This includes items, such as the Input Change Notification (ICN) on the I/O ports or peripherals that use an external clock input. Any peripheral that requires the system clock source for its operation will be disabled in Sleep mode.

The device will wake-up from Sleep mode on any of these events:

- On any interrupt source that is individually enabled
- On any form of device Reset
- On a WDT time-out

On wake-up from Sleep, the processor will restart with the same clock source that was active when Sleep mode was entered.

10.2.2 IDLE MODE

Idle mode has these features:

- The CPU will stop executing instructions.
- The WDT is automatically cleared.
- The system clock source remains active. By default, all peripheral modules continue to operate normally from the system clock source, but can also be selectively disabled (see **Section 10.5 “Selective Peripheral Module Control”**).
- If the WDT or FSCM is enabled, the LPRC will also remain active.

The device will wake from Idle mode on any of these events:

- Any interrupt that is individually enabled
- Any device Reset
- A WDT time-out

On wake-up from Idle, the clock is re-applied to the CPU. Instruction execution begins immediately, starting with the instruction following the PWRSAV instruction or the first instruction in the ISR.

10.2.3 INTERRUPTS COINCIDENT WITH POWER SAVE INSTRUCTIONS

Any interrupt that coincides with the execution of a PWRSAV instruction will be held off until entry into Sleep or Idle mode has completed. The device will then wake-up from Sleep or Idle mode.

REGISTER 16-5: PSTR1CON: ECCP1 PULSE STEERING CONTROL REGISTER(1)

U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0
—	—	—	—	—	—	—	—
bit 15							bit 8

R/W-0	R/W-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-1
CMPL1	CMPL0	—	STRSYNC	STRD	STRC	STRB	STRA
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'	
-n = Value at POR	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 15-8 **Unimplemented:** Read as '0'

bit 7-6 **CMPL<1:0>:** Complementary Mode Output Assignment Steering bits
- 00 = Complementary output assignment is disabled; the STR<D:A> bits are used to determine Steering mode
- 01 = P1A and P1B are selected as the complementary output pair
- 10 = P1A and P1C are selected as the complementary output pair
- 11 = P1A and P1D are selected as the complementary output pair

bit 5 **Unimplemented:** Read as '0'

bit 4 **STRSYNC:** Steering Sync bit
- 1 = Output steering update occurs on the next PWM period
- 0 = Output steering update occurs at the beginning of the instruction cycle boundary

bit 3 **STRD:** Steering Enable D bit
- 1 = P1D pin has the PWM waveform with polarity control from CCP1M<1:0>
- 0 = P1D pin is assigned to port pin

bit 2 **STRC:** Steering Enable C bit
- 1 = P1C pin has the PWM waveform with polarity control from CCP1M<1:0>
- 0 = P1C pin is assigned to port pin

bit 1 **STRB:** Steering Enable B bit
- 1 = P1B pin has the PWM waveform with polarity control from CCP1M<1:0>
- 0 = P1B pin is assigned to port pin

bit 0 **STRA:** Steering Enable A bit
- 1 = P1A pin has the PWM waveform with polarity control from CCP1M<1:0>
- 0 = P1A pin is assigned to port pin

Note 1: This register is only implemented on PIC24FXXKL40X/30X devices. In addition, PWM Steering mode is available only when CCP1M<3:2> = 11 and PM<1:0> = 00.

18.1 UART Baud Rate Generator (BRG)

The UART module includes a dedicated 16-bit Baud Rate Generator (BRG). The UxBRG register controls the period of a free-running, 16-bit timer. Equation 18-1 provides the formula for computation of the baud rate with BRGH = 0.

EQUATION 18-1: UARTx BAUD RATE WITH BRGH = 0(1)

$$\text{Baud Rate} = \frac{FCY}{16 \bullet (UxBRG + 1)}$$

$$UxBRG = \frac{FCY}{16 \bullet \text{Baud Rate}} - 1$$

Note 1: Based on FCY = FOSC/2; Doze mode and PLL are disabled.

Example 18-1 provides the calculation of the baud rate error for the following conditions:

- FCY = 4 MHz
- Desired Baud Rate = 9600

The maximum baud rate (BRGH = 0) possible is FCY/16 (for UxBRG = 0) and the minimum baud rate possible is FCY/(16 * 65536).

Equation 18-2 shows the formula for computation of the baud rate with BRGH = 1.

EQUATION 18-2: UARTx BAUD RATE WITH BRGH = 1(1)

$$\text{Baud Rate} = \frac{FCY}{4 \bullet (UxBRG + 1)}$$

$$UxBRG = \frac{FCY}{4 \bullet \text{Baud Rate}} - 1$$

Note 1: Based on FCY = FOSC/2; Doze mode and PLL are disabled.

The maximum baud rate (BRGH = 1) possible is FCY/4 (for UxBRG = 0) and the minimum baud rate possible is FCY/(4 * 65536).

Writing a new value to the UxBRG register causes the BRG timer to be reset (cleared). This ensures the BRG does not wait for a timer overflow before generating the new baud rate.

EXAMPLE 18-1: BAUD RATE ERROR CALCULATION (BRGH = 0)(1)

Desired Baud Rate = FCY/(16 (UxBRG + 1))

Solving for UxBRG Value:

UxBRG = ((FCY/Desired Baud Rate)/16) – 1
UxBRG = ((4000000/9600)/16) – 1
UxBRG = 25

Calculated Baud Rate = 4000000/(16 (25 + 1))
= 9615

Error = (Calculated Baud Rate – Desired Baud Rate) / Desired Baud Rate
= (9615 – 9600)/9600
= 0.16%

Note 1: Based on FCY = FOSC/2; Doze mode and PLL are disabled.

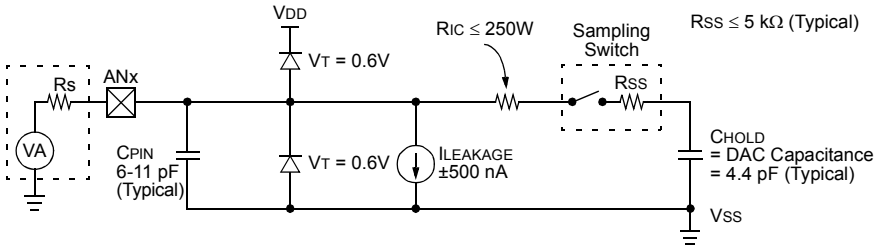
EQUATION 19-1: A/D CONVERSION CLOCK PERIOD(1)

$$ADCS = \frac{TAD}{TCY} - 1$$

$$TAD = TCY \bullet (ADCS + 1)$$

Note 1: Based on TCY = 2 * TOSC; Doze mode and PLL are disabled.

FIGURE 19-2: 10-BIT A/D CONVERTER ANALOG INPUT MODEL



Legend:		
	CPIN	= Input Capacitance
	VT	= Threshold Voltage
	ILEAKAGE	= Leakage Current at the pin due to Various Junctions
	RIC	= Interconnect Resistance
	RSS	= Sampling Switch Resistance
	CHOLD	= Sample/Hold Capacitance (from DAC)

Note: CPIN value depends on device package and is not tested. Effect of CPIN is negligible if Rs ≤ 5 kΩ.

21.0 COMPARATOR VOLTAGE REFERENCE

Note: This data sheet summarizes the features of this group of PIC24F devices. It is not intended to be a comprehensive reference source. For more information on the Comparator Voltage Reference, refer to the *"dsPIC33/PIC24 Family Reference Manual"*, **"Comparator Voltage Reference Module"** (DS39709).

21.1 Configuring the Comparator Voltage Reference

The comparator voltage reference module is controlled through the CVRCON register (Register 21-1). The comparator voltage reference provides a range of output voltages, with 32 distinct levels.

The comparator voltage reference supply voltage can come from either VDD and VSS, or the external VREF+ and VREF-. The voltage source is selected by the CVRSS bit (CVRCON<5>).

The settling time of the comparator voltage reference must be considered when changing the CVREF output.

FIGURE 21-1: COMPARATOR VOLTAGE REFERENCE BLOCK DIAGRAM

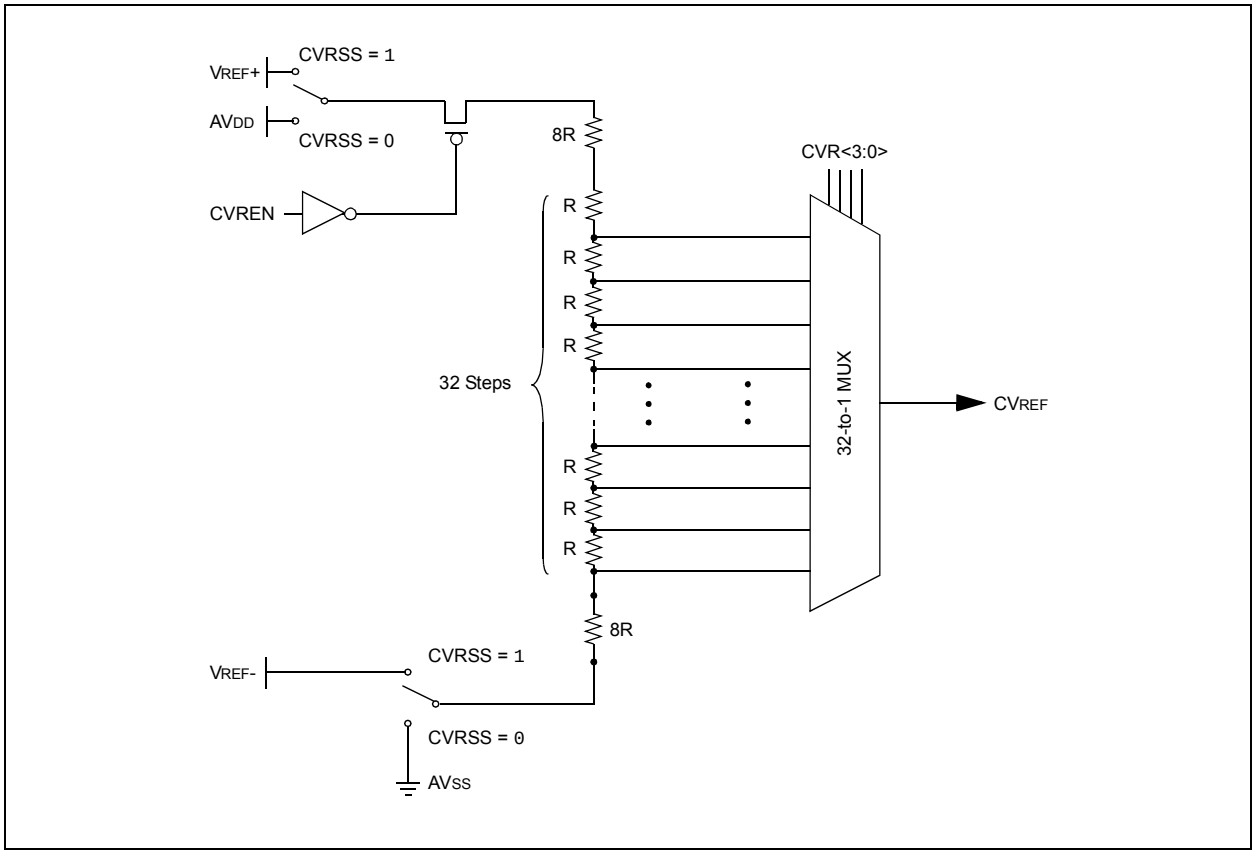


TABLE 25-1: SYMBOLS USED IN OPCODE DESCRIPTIONS

Field	Description
#text	Means literal defined by "text"
(text)	Means "content of text"
[text]	Means "the location addressed by text"
{ }	Optional field or operation
<n:m>	Register bit field
.b	Byte mode selection
.d	Double-Word mode selection
.S	Shadow register select
.w	Word mode selection (default)
bit4	4-bit bit selection field (used in word addressed instructions) ∈ {0...15}
C, DC, N, OV, Z	MCU Status bits: Carry, Digit Carry, Negative, Overflow, Sticky Zero
Expr	Absolute address, label or expression (resolved by the linker)
f	File register address ∈ {0000h...1FFFh}
lit1	1-bit unsigned literal ∈ {0,1}
lit4	4-bit unsigned literal ∈ {0...15}
lit5	5-bit unsigned literal ∈ {0...31}
lit8	8-bit unsigned literal ∈ {0...255}
lit10	10-bit unsigned literal ∈ {0...255} for Byte mode, {0:1023} for Word mode
lit14	14-bit unsigned literal ∈ {0...16384}
lit16	16-bit unsigned literal ∈ {0...65535}
lit23	23-bit unsigned literal ∈ {0...8388608}; LSB must be '0'
None	Field does not require an entry, may be blank
PC	Program Counter
Slit10	10-bit signed literal ∈ {-512...511}
Slit16	16-bit signed literal ∈ {-32768...32767}
Slit6	6-bit signed literal ∈ {-16...16}
Wb	Base W register ∈ {W0..W15}
Wd	Destination W register ∈ { Wd, [Wd], [Wd++], [Wd--], [++Wd], [--Wd] }
Wdo	Destination W register ∈ { Wnd, [Wnd], [Wnd++], [Wnd--], [++Wnd], [--Wnd], [Wnd+Wb] }
Wm,Wn	Dividend, Divisor Working register pair (direct addressing)
Wn	One of 16 Working registers ∈ {W0..W15}
Wnd	One of 16 destination Working registers ∈ {W0..W15}
Wns	One of 16 source Working registers ∈ {W0..W15}
WREG	W0 (Working register used in File register instructions)
Ws	Source W register ∈ { Ws, [Ws], [Ws++], [Ws--], [++Ws], [--Ws] }
Wso	Source W register ∈ { Wns, [Wns], [Wns++], [Wns--], [++Wns], [--Wns], [Wns+Wb] }

FIGURE 26-4: EXTERNAL CLOCK TIMING

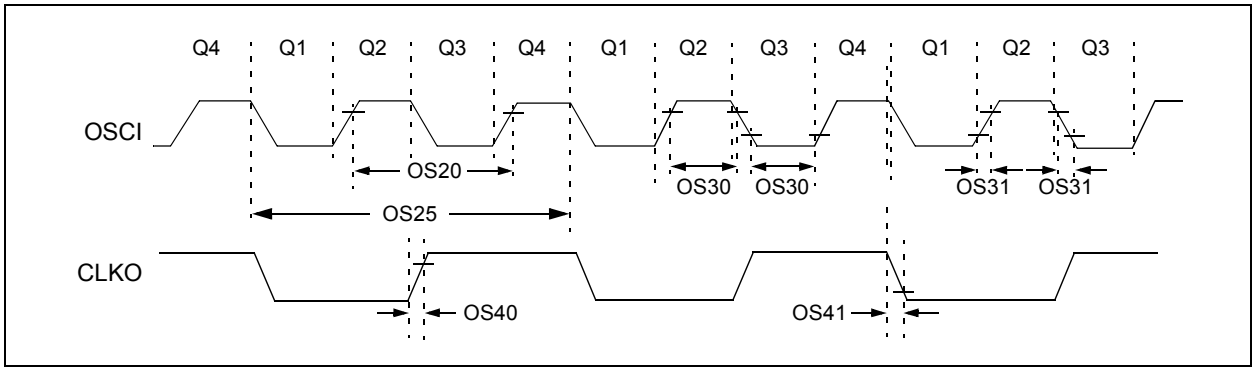


TABLE 26-18: EXTERNAL CLOCK TIMING REQUIREMENTS

AC CHARACTERISTICS			Standard Operating Conditions: 1.8V to 3.6V Operating temperature -40°C ≤ TA ≤ +85°C for Industrial -40°C ≤ TA ≤ +125°C for Extended				
Param No.	**Sym**	**Characteristic**	**Min**	**Typ(1)**	**Max**	**Units**	**Conditions**
OS10	FOSC	External CLKI Frequency (External clocks allowed only in EC mode)	DC 4	— —	32 8	MHz MHz	EC ECPLL
		Oscillator Frequency	0.2 4 4 31	— — — —	4 25 8 33	MHz MHz MHz kHz	XT HS HSPLL SOSC
OS20	TOSC	TOSC = 1/FOSC	—	—	—	—	See Parameter OS10 for FOSC value
OS25	TCY	Instruction Cycle Time(2)	62.5	—	DC	ns	
OS30	TosL, TosH	External Clock in (OSCI) High or Low Time	0.45 x TOSC	—	—	ns	EC
OS31	TosR, TosF	External Clock in (OSCI) Rise or Fall Time	—	—	20	ns	EC
OS40	TckR	CLKO Rise Time(3)	—	6	10	ns	
OS41	TckF	CLKO Fall Time(3)	—	6	10	ns	

Note 1: Data in “Typ” column is at 3.3V, +25°C unless otherwise stated. Parameters are for design guidance only and are not tested.

2: Instruction cycle period (TCY) equals two times the input oscillator time base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at “Min.” values with an external clock applied to the OSCI/CLKI pin. When an external clock input is used, the “Max.” cycle time limit is “DC” (no clock) for all devices.

3: Measurements are taken in EC mode. The CLKO signal is measured on the OSCO pin. CLKO is low for the Q1-Q2 period (1/2 TCY) and high for the Q3-Q4 period (1/2 TCY).

TABLE 26-36: A/D CONVERSION TIMING REQUIREMENTS(1)

AC CHARACTERISTICS			Standard Operating Conditions: 1.8V to 3.6V (unless otherwise stated) Operating temperature -40°C ≤ TA ≤ +85°C for Industrial				
Param No.	**Symbol**	**Characteristic**	**Min.**	**Typ**	**Max.**	**Units**	**Conditions**
Clock Parameters							
AD50	TAD	A/D Clock Period	75	—	—	ns	TCY = 75 ns, AD1CON3 is in default state
AD51	TRC	A/D Internal RC Oscillator Period	—	250	—	ns	
Conversion Rate							
AD55	TCONV	Conversion Time	—	12	—	TAD	
AD56	FCNV	Throughput Rate	—	—	500	ksps	AVDD ≥ 2.7V
AD57	TSAMP	Sample Time	—	1	—	TAD	
AD58	TACQ	Acquisition Time	750	—	—	ns	**(Note 2)**
AD59	TSWC	Switching Time from Convert to Sample	—	—	**(Note 3)**	—	
AD60	TDIS	Discharge Time	0.5	—	—	TAD	
Clock Parameters							
AD61	TPSS	Sample Start Delay from Setting Sample bit (SAMP)	2	—	3	TAD	

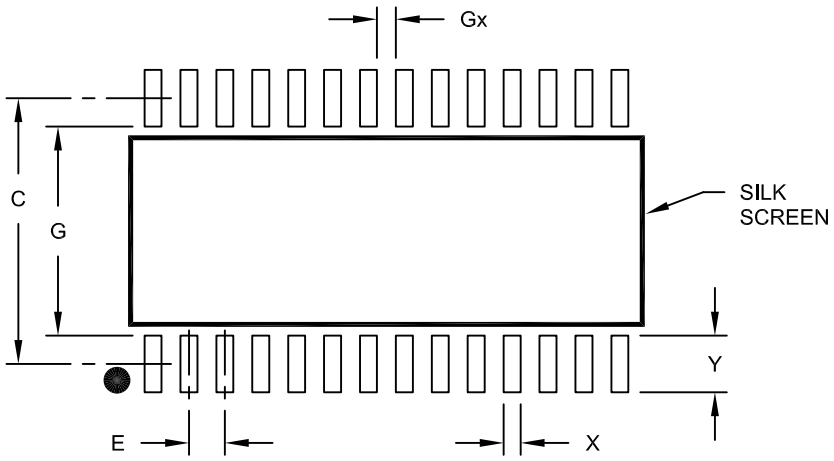
Note 1: Because the sample caps will eventually lose charge, clock rates below 10 kHz can affect linearity performance, especially at elevated temperatures.

2: The time for the holding capacitor to acquire the “New” input voltage when the voltage changes full scale after the conversion (VDD to VSS or VSS to VDD).

3: On the following cycle of the device clock.

28-Lead Plastic Small Outline (SO) - Wide, 7.50 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	C		9.40	
Contact Pad Width (X28)	X			0.60
Contact Pad Length (X28)	Y			2.00
Distance Between Pads	Gx	0.67		
Distance Between Pads	G	7.40		

Notes:

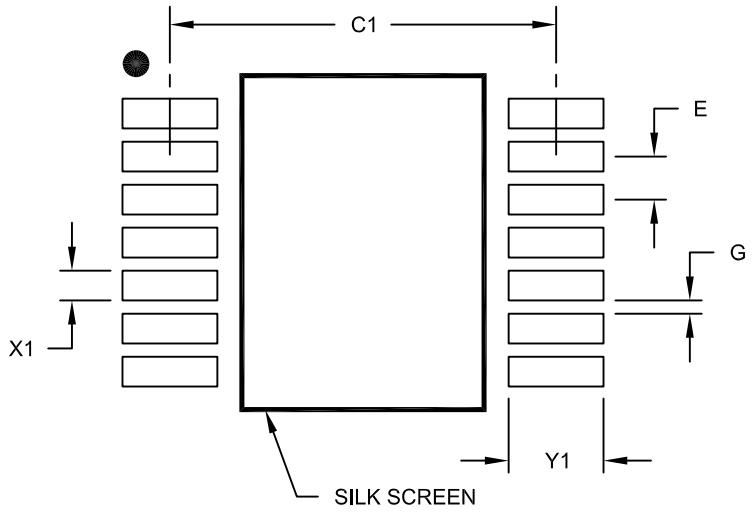
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2052A

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X14)	X1			0.45
Contact Pad Length (X14)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

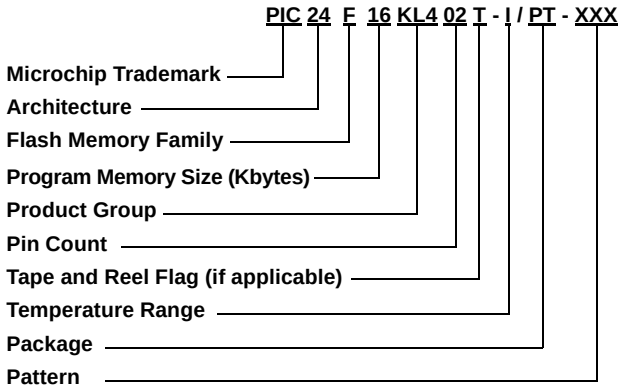
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2087A

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.



Architecture	24	= 16-bit modified Harvard without DSP
Flash Memory Family	F	= Standard voltage range Flash program memory
Product Group	KL4 KL3 KL2 KL1	= General purpose microcontrollers
Pin Count	00 01 02	= 14-pin = 20-pin = 28-pin
Temperature Range	I E	= -40°C to +85°C (Industrial) = -40°C to +125°C (Extended)
Package	SP SO SS ST ML, MQ P	= SPDIP = SOIC = SSOP = TSSOP = QFN = PDIP
Pattern	Three-digit QTP, SQTP, Code or Special Requirements (blank otherwise) ES	= Engineering Sample

Examples:

a) PIC24F16KL402-I/ML: General Purpose, 16-Kbyte Program Memory, 28-Pin, Industrial Temperature, QFN Package

b) PIC24F04KL101T-I/SS: General Purpose, 4-Kbyte Program Memory, 20-Pin, Industrial Temperature, SSOP Package, Tape-and-Reel